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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Christoph A. Wasshuber Art Unit: 2818
Serial No.: 10/714,366 Examiner: Nguyen, T.
Filing Date: 11/13/2003 Docket No.: TI-36280
Customer No.: 23494 Conf. No.: 1864

Title: FORMING A SEMICONDUCTOR STRUCTURE IN MANUFACTURING A SEMICONDUCTOR DEVICE USING ONE OR MORE EPITAXIAL GROWTH PROCESSES

ELECTION

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

MAILING CERTIFICATE UNDER 37 C.F.R. § 1.8(A)
I hereby certify that the above correspondence is being deposited with the U.S. Postal Service as first Class Mail in an envelope addressed to Commissioner for Patents, PO Box 1450, Alexandria, VA 22313-1450.

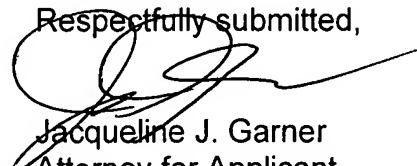
Date

Marianna Smith

Dear Sir:

With respect to the Restriction Requirement mailed on 02/07/2005, the Examiner has restricted the instant application to the invention of Group I (Claims 1-11), or Group II (Claims 12-20). In light of this, Applicant elects to pursue Group I, (Claims 1-11) without traverse.

Respectfully submitted,


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